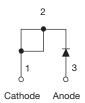
VS-10ETF1...FPPbF Series, VS-10ETF1...FP-M3 Series

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Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 10 A





PRODUCT SUMMARY					
Package	TO-220FP				
I _{F(AV)}	10 A				
V _R	1000 V, 1200 V				
V _F at I _F	1.33 V				
I _{FSM}	140 A				
t _{rr}	80 ns				
T _J max.	150 °C				
Diode variation	Single die				
Snap factor	0.6				

FEATURES

- · Glass passivated pellet chip junction
- 150 °C max. operation junction temperature
- Designed and qualified according to JEDEC®-JESD 47
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL E78996 approved
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-10ETF1..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
V _{RRM}		1000 to 1200	V		
I _{F(AV)}	Sinusoidal waveform	10	Δ.		
I _{FSM}		140	A		
t _{rr}	1 A, 100 A/μs	80	ns		
V _F	10 A, T _J = 25 °C	1.33	V		
T _J		-40 to +150	°C		

VOLTAGE RATINGS					
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA		
VS-10ETF10FPPbF, VS-10ETF10FP-M3	1000	1100	4		
VS-10ETF12FPPbF, VS-10ETF12FP-M3	1200	1300	4		

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS VAL		UNITS
Maximum average forward current	I _{F(AV)}	T _C = 95 °C, 180° conduction half sine wave	10	
Maximum peak one cycle	I	10 ms sine pulse, rated V _{RRM} applied	115	Α
non-repetitive surge current	I _{FSM}	10 ms sine pulse, no voltage reapplied	140	
Maximum I ² t for fusing I ² t	I ² t	10 ms sine pulse, rated V _{RRM} applied	66	A ² s
I Waxiiridiii i-t ioi iusiiig		10 ms sine pulse, no voltage reapplied	94	A-5
Maximum I²√t for fusing	$l^2\sqrt{t}$ $t = 0.1$ to 10 ms, no voltage reapplied		940	A ² √s



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM}	10 A, T _J = 25 °C		1.33	V
Forward slope resistance	r _t	− T _J = 150 °C		22.9	mΩ
Threshold voltage	V _{F(TO)}			0.96	V
Maximum rayaraa laakaga aurrant	1	T _J = 25 °C	V Doted V	0.1	mA
Maximum reverse leakage current	I _{RM}	T _J = 150 °C	V _R = Rated V _{RRM}	4	IIIA

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •
Reverse recovery time	t _{rr}	L at 10 Δ .	310	ns	I _{FM}
Reverse recovery current	I _{rr}	l _F at 10 A _{pk} 25 A/µs	4.7	А	t _{rr}
Reverse recovery charge	Q _{rr}	25 °C	1.05	μC	dir/ dt Q _{rr}
Snap factor	S		0.6		I _{RM(REC)}

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and sto temperature range	rage	T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resistar junction to case	ice	R _{thJC}	DC operation	2.5	
Maximum thermal resistar junction to ambient	ice	R _{thJA}		62	°C/W
Typical thermal resistance case to heatsink	,	R _{thCS}	Mounting surface, smooth, and greased	0.5	
A consistence to constant			2	g	
Approximate weight	Approximate weight			0.07	OZ.
Mounting torque minimum maximum				6 (5)	kgf ⋅ cm
				12 (10)	(lbf \cdot in)
Marking device			Case style TO-220 FULL-PAK	10ETF 10ETF	

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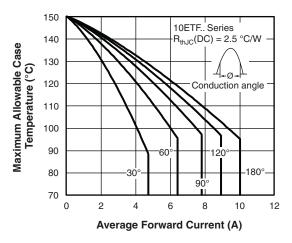


Fig. 1 - Current Rating Characteristics

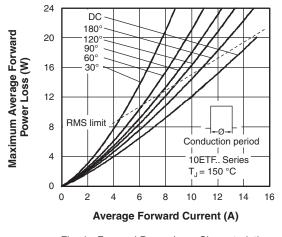


Fig. 4 - Forward Power Loss Characteristics

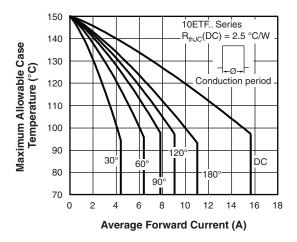


Fig. 2 - Current Rating Characteristics

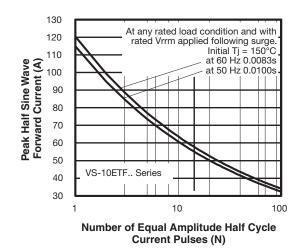


Fig. 5 - Maximum Non-Repetitive Surge Current

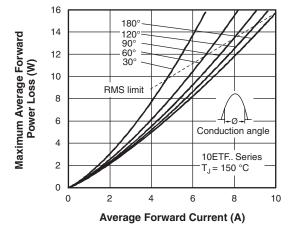


Fig. 3 - Forward Power Loss Characteristics

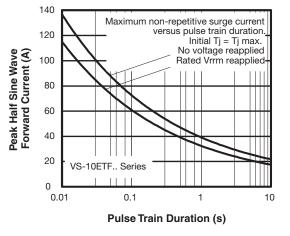


Fig. 6 - Maximum Non-Repetitive Surge Current

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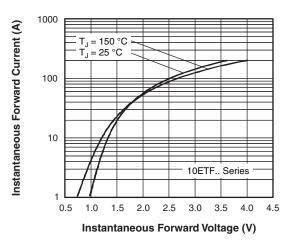


Fig. 7 - Forward Voltage Drop Characteristics

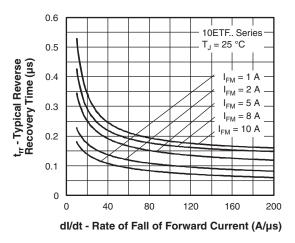


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

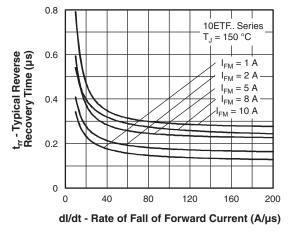


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

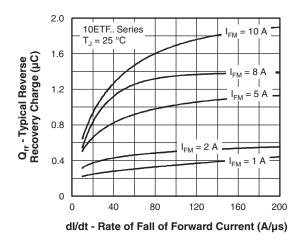


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

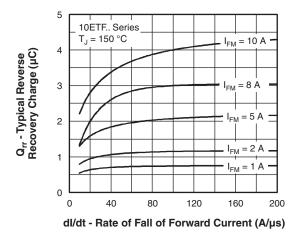


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

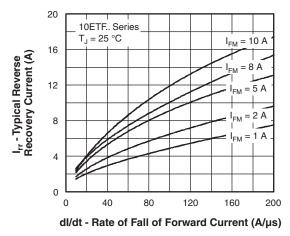


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

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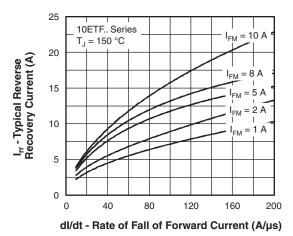


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

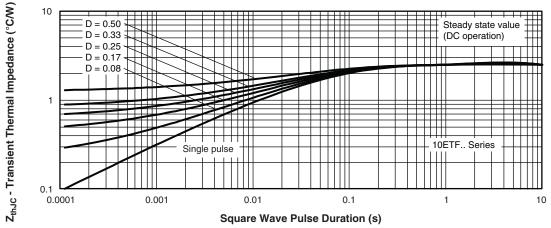


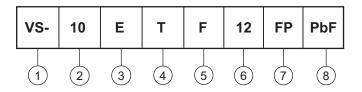
Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (10 = 10 A)

Circuit configuration:

E = single diode

4 - Package:

T = TO-220

5 - Type of silicon:

F = fast soft recovery rectifier

02 = 200 V

Voltage code x 100 = V_{RRM} -

04 = 400 V 06 = 600 V

7 - FULL-PAK

8 - Environmental digit:

• PbF = lead (Pb)-free and RoHS-compliant

• -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

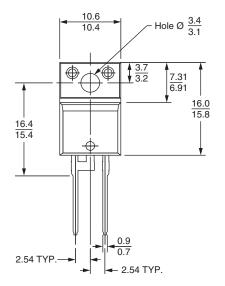
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-10ETF10FPPbF	50	1000	Antistatic plastic tubes			
VS-10ETF10FP-M3	50	1000	Antistatic plastic tubes			
VS-10ETF12FPPbF	50	1000	Antistatic plastic tubes			
VS-10ETF12FP-M3	50	1000	Antistatic plastic tubes			

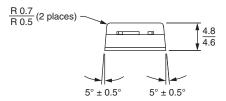
LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95005				
Dout moulting information	TO-220 FP PbF	www.vishay.com/doc?95009		
Part marking information	TO-220 FP -M3	www.vishay.com/doc?95440		

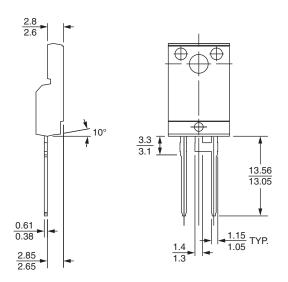


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DIMENSIONS in millimeters







Lead assignments

Diodes

1 + 2 - Cathode

3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK



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